

2SAR512P

PNP -2.0A -30V Middle Power Transistor

				●Outline			
Parameter	Va	alue		MPT3			
V _{CEO}	-3	30V					
I _C	-2	.0A		Base 🧳 Collector	\mathbf{X}		
		_		Em			
●Features				-	R512P		
 Features Suitable for Middle 		vor			-62) T-89> ▲		
2) Complementary N)	-00			
3) Low V _{CE(sat)}	Пітурез	. 20010121					
$V_{CE(sat)} = -0.4V(Ma)$	ax.)						
(I _C /I _B = -700mA/ -							
4) Lead Free/RoHS	Compliant.						
,						6	
●Inner circuit							
Collector							
o I				 Applicati 	ons		
	Base			Motor drive	r , LED drive	er	
				Power supp	oly		
o Emitter							
Packaging specifi	cations						
er dendging opeen		Package				Basic	
Part No.	Package	size	Taping	Reel size	Tape width	ordering	Marking
		(mm)	code	(mm)	(mm)	unit (pcs)	_
2SAR512P	MPT3	4540	T100	180	12	1,000	MB
			-	L	<u>.</u>		
Absolute maximu	m ratings	(Ta = 25°C)					
	Parameter			Symbol	Va	alues	Unit
Collector-base voltage				V _{CBO}	-30		V
Collector-emitter voltage				V_{CEO}	-30		V
Emitter-base voltage				V_{EBO}	-6		V
Collector ourrent		DC		I _C	-	-2.0	A
Collector current		Pulsed		I_{CP}^{*1}		-4.0	Α
Power discipation			P_D^{*2}	0.5		W	
Power dissipation				P_{D}^{*3}	2.0		W
Junction temperature				Τ _j	150		°C
Range of storage ter	nperature			T _{stg}	-55	to +150	°C
*1 Pw=10ms , sir	gle pulse						

4

*2 Each terminal mounted on a reference land

*3 Mounted on a ceramic board (40×40×0.7mm)

•Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	I _C = -1mA	-30	-	-	V
Collector-base breakdown voltage	BV _{CBO}	I _C = -100μA	-30	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	I _E = -100μA	-6	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = -30V	-	-	-1	μA
Emitter cut-off current	I _{EBO}	V _{EB} = -4V	-	-	-1	μA
Collector-emitter saturation voltage	V _{CE(sat)} ^{*1}	I _C = -700mA, I _B = -35mA	0	-0.20	-0.40	V
DC current gain	h _{FE}	$V_{CE} = -2V, I_{C} = -100 \text{mA}$	200	-	500	-
Transition frequency	f _⊤	V _{CE} = -10V, I _E = -100mA f=100MHz	-	430	-	MHz
Output capacitance	C _{ob}	V _{CB} = -10V, I _E = 0A, f = 1MHz	-	15	-	pF
Turn-on time	t _{on} *2	I _c = -1A		30	-	ns
Storage time	t _{stg} *2	I _{B1} = -100mA I _{B2} =100mA	-	170	-	ns
Fall time	t _f *2	V _{CC} ≃ -10V	-	15	-	ns
*4						

*1 Pulsed

*2 See switching time test circuit

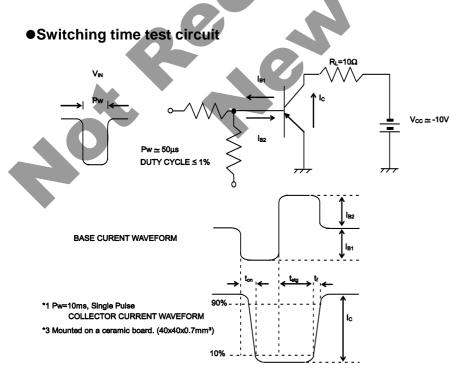


Fig.2 Typical Output Characteristics

•Electrical characteristic curves(Ta = 25°C)

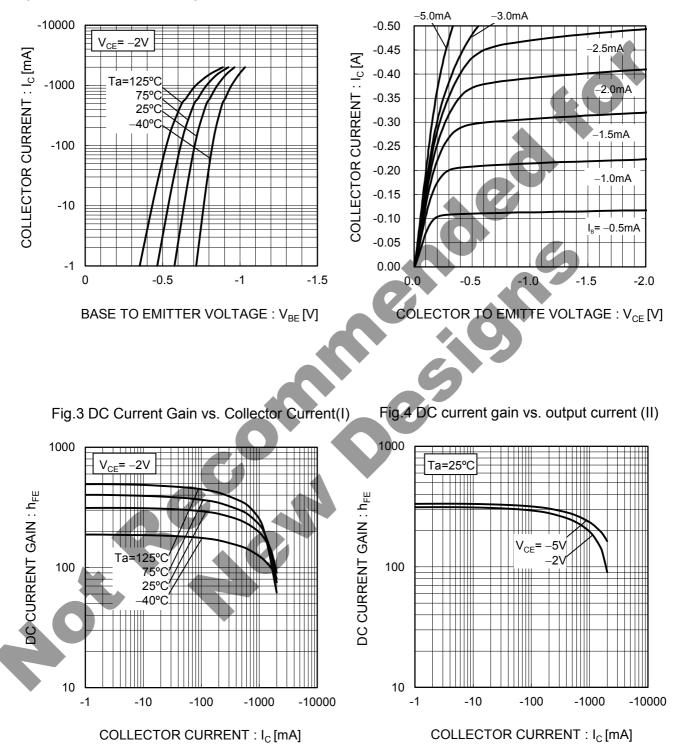
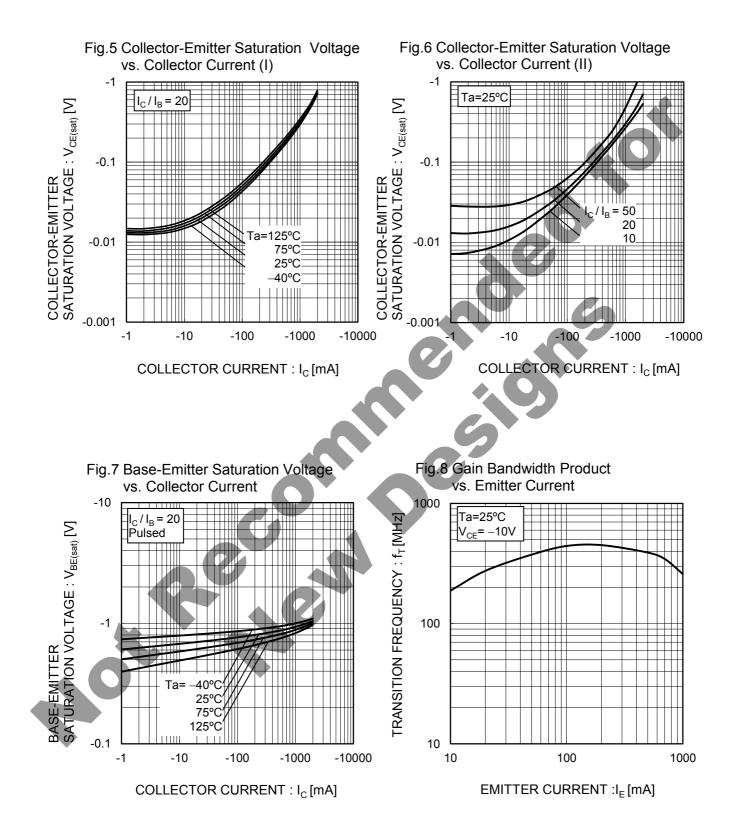
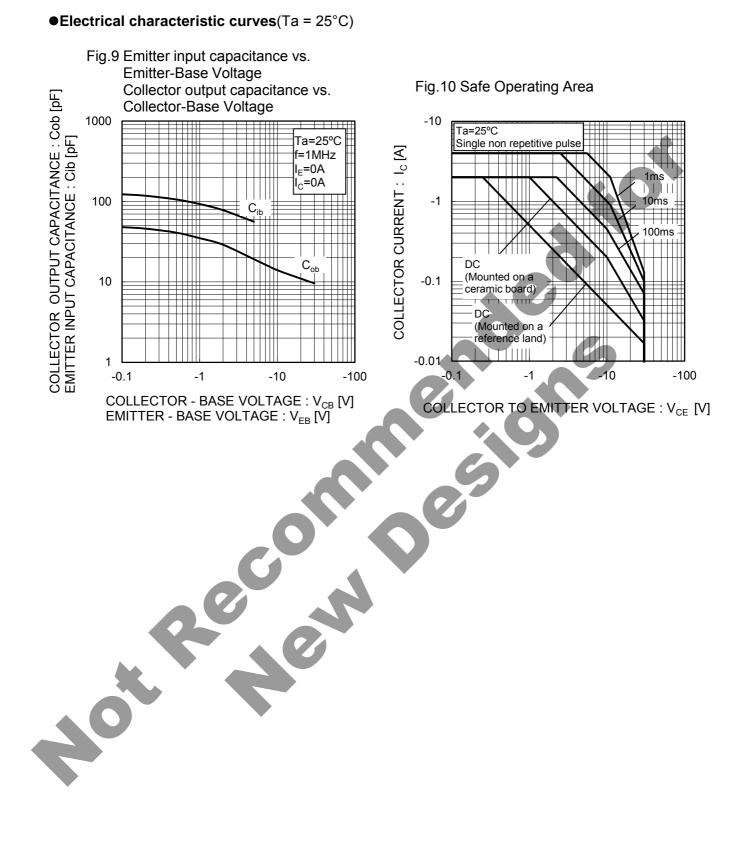


Fig.1 Ground Emitter Propagation Characteristics

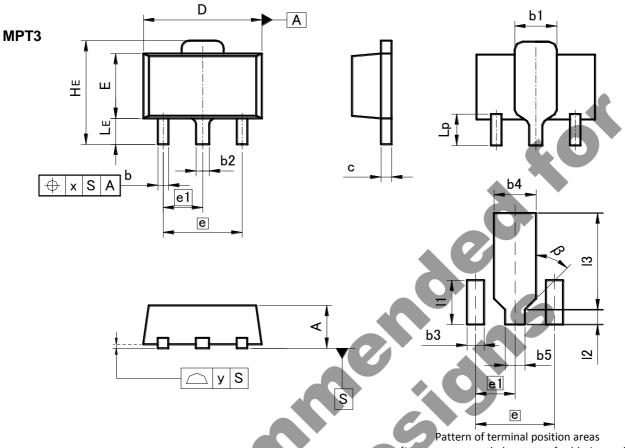
•Electrical characteristic curves(Ta = 25°C)





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•Dimensions (Unit : mm)



[Not a recommended pattern of soldering pads]

DIM	MILIM	TERS	INC	HES
DIM	MIN	MAX	MIN	MAX
A	1.40	1.50	0.055	0.059
b	0.30	0.50	0.012	0.020
b1	1.50	1.70	0.059	0.067
b2	0.40	0.60	0.016	0.024
(0	0.35	0.50	0.014	0.020
D	4.40	4.70	0.173	0.185
ш	2.40	2.70	0.094	0.106
е	3.0	00	0.1	18
e1		50	0.0	59
HE	3.70	4.30	0.146	0.169
Le	0.80	1.20	0.031	0.047
Lp	1.01	1.41	0.040	0.056
х	-	0.15	-	0.006
У	-	0.10	-	0.004
DIM	MILIM	ETERS	INC	HES
	MIN	MAX	MIN	MAX
<u>ل</u> م		0.05		0.000

DIM —	MILIM	ETERS	INCHES		
	MIN	MAX	MIN	MAX	
b3	-	0.65	-	0.026	
b4	-	1.70	-	0.067	
b5	-	0.75	-	0.030	
1	-	1.71	-	0.067	
12	-	0.58	-	0.023	
13	-	3.72	-	0.146	
β	45	0	45	0	

Dimension in mm / inches

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